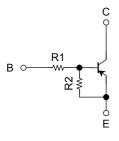
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process) (Bias Resistor built-in Transistor)

RN2701JE,RN2702JE,RN2703JE RN2704JE,RN2705JE,RN2706JE

Switching, Inverter Circuit, Interface Circuit and Driver Circuit Applications.

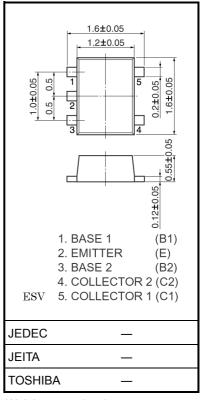
- Two devices are incorporated into an Extreme-Super-Mini (5 pin) package.
- Incorporating a bias resistor into a transistor reduces parts count.
 Reducing the parts count enable the manufacture of ever more compact equipment and save assembly cost.
- Complementary to RN1701JE~RN1706JE

Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN2701JE	4.7	4.7
RN2702JE	10	10
RN2703JE	22	22
RN2704JE	47	47
RN2705JE	2.2	47
RN2706JE	4.7	47

Unit: mm



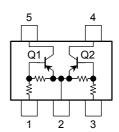
Weight: g (typ.)

Maximum Ratings (Ta = 25°C) (Q1, Q2 common)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage	RN2701JE~RN2706JE	V _{CBO}	-50	V	
Collector-emitter voltage	TANZI O ISL TANZI OOSL	V_{CEO}	-50	V	
Emitter-base voltage	RN2701JE~RN2704JE	V _{EBO}	-10	V	
Litiliter-base voltage	RN2705JE, RN2706JE	v EBO	-5		
Collector current		Ic	-100	mA	
Collector power dissipation	RN2701JE~RN2706JE	P _C (Note)	100	mW	
Junction temperature	temperature		150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

Note: Total rating

Equivalent Circuit (top view)

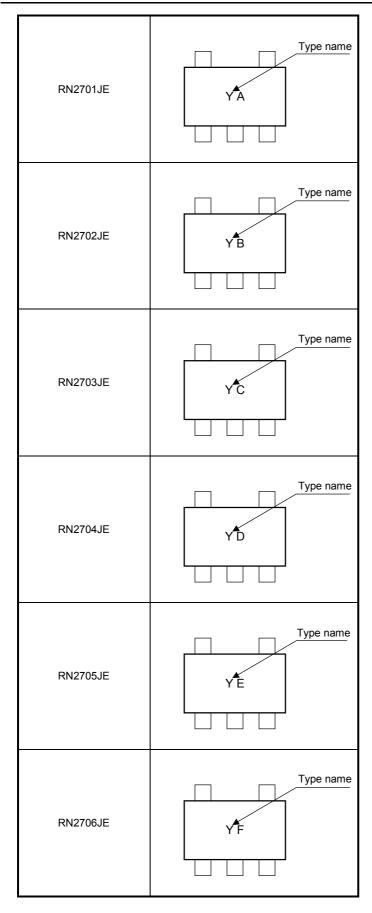




Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN2701JE~2706JE	I _{CBO}	$V_{CB} = -50 \text{ V}, I_E = 0$	_	_	-100	nA
Collector cut-on current	KN27013L*27003L	I _{CEO}	$V_{CE} = -50 \text{ V}, I_B = 0$	_	_	-500	IIA
	RN2701JE			-0.82	_	-1.52	
	RN2702JE	Isso	$V_{EB} = -10 \text{ V}, I_C = 0$	-0.38	_	-0.71	m A
Emitter cut-off current	RN2703JE			-0.17	_	-0.33	
Emiller cut-on current	RN2704JE	- I _{EBO}		-0.082	_	-0.15	mA
	RN2705JE		V 5 V I - 0	-0.078	_	-0.145	
	RN2706JE		$V_{EB} = -5 \text{ V, } I_{C} = 0$	-0.074	_	-0.138	
	RN2701JE		$V_{CE} = -5 \text{ V},$ $I_{C} = -10 \text{ mA}$	30	_	_	
	RN2702JE	=		50	_	_	
DC ourrent gain	RN2703JE	h		70	_	_	
DC current gain	RN2704JE	- h _{FE}		80	_	_	
	RN2705JE	-		80	_	_	
	RN2706JE			80	_	_	
Collector-emitter saturation voltage	RN2701JE~2706JE	V _{CE (sat)}	$\begin{split} I_C &= -5 \text{ mA}, \\ I_B &= -0.25 \text{ mA} \end{split}$	_	-0.1	-0.3	٧
	RN2701JE	V _{I (ON)}	$V_{CE} = -0.2 \text{ V},$ $I_{C} = -5 \text{ mA}$	-1.1	_	-2.0	V
	RN2702JE			-1.2	_	-2.4	
Innut valtage (ON)	RN2703JE			-1.3	_	-3.0	
Input voltage (ON)	RN2704JE			-1.5	_	-5.0	
	RN2705JE			-0.6	_	-1.1	
	RN2706JE			-0.7	_	-1.3	
Innut voltage (OFF)	RN2701JE~2704JE	V	$V_{CE} = -5 \text{ V},$ $I_{C} = -0.1 \text{ mA}$	-1.0	_	-1.5	V
Input voltage (OFF)	RN2705JE, 2706JE	V _{I (OFF)}		-0.5	_	-0.8	
Transition frequency	RN2701JE~2706JE	f _T	$V_{CE} = -10 \text{ V},$ $I_{C} = -5 \text{ mA}$	_	200		MHz
Collector output capacitance	RN2701JE~2706JE	C _{ob}	$V_{CB} = -10 \text{ V}, I_E = 0,$ f = 1 MHz	_	3	6	pF
	RN2701JE			3.29	4.7	6.11	
	RN2702JE	- R1	_	7	10	13	kΩ
Innut register	RN2703JE			15.4	22	28.6	
Input resistor	RN2704JE			32.9	47	61.1	
	RN2705JE			1.54	2.2	2.86	
	RN2706JE]		3.29	4.7	6.11	
	RN2701JE~2704JE		_	0.9	1.0	1.1	
Resistor ratio	RN2705JE	R1/R2		0.0421	0.0468	0.0515	
	RN2706JE			0.09	0.1	0.11	

Type Name Marking



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